

GENERAL DESCRIPTION

The SGM3833A and SGM3833B are designed to drive AMOLED displays (Active Matrix Organic Light Emitting Diode) requiring V_{AVDD} , V_{ELVDD} and V_{ELVSS} . The devices integrate a boost converter for V_{EUVDD} , an inverting buck-boost converter for V_{ELVSS} and a boost converter for V_{AVDD} , which are suitable for battery operated products. The digital interface control pin (CTRL) allows programming V_{AVDD} , V_{ELVDD} and V_{ELVSS} in digital steps.

The SGM3833A and SGM3833B are both available in Green TQFN-3×3-16L packages. They operate over an ambient temperature range of -40℃ to +85℃.

FEATURES

- **2.9V to 4.5V Input Voltage Range**
- **Synchronous Boost Converter (AVDD)**
	- **5.8V to 7.9V Output Voltage (Programmable)**
	- **7.6V Default Output Voltage**
	- **1.2% Accuracy**
	- **100mA Output Current Capability**
	- \bullet V_{IN} to V_{OUT} and V_{OUT} to V_{IN} Isolation
- **Synchronous Boost Converter (ELVDD)**
	- **4.6V to 5.0V Output Voltage (Programmable)**
	- **4.6V Default Output Voltage**

TYPICAL APPLICATION

- **1.2% Accuracy**
- **400mA Output Current Capability**
- **External Output Voltage Sensing Pin for Load Drop Compensation**
- \bullet V_{IN} to V_{OUT} and V_{OUT} to V_{IN} Isolation
- **Synchronous Inverting Buck-Boost Converter (ELVSS)**
	- **SGM3833A:**
	- **-4.8V to -0.8V Output Voltage (Programmable)**
	- **SGM3833B:**
	- **-5.4V to -1.4V Output Voltage (Programmable)**
	- **-4.0V Default Output Voltage**
	- **1.5% Accuracy at -4.0V (±60mV)**
	- **400mA Output Current Capability**
	- \bullet V_{IN} to V_{OUT} and V_{OUT} to V_{IN} Isolation
- **Short Circuit Protection**
- **Thermal Shutdown**
- **VELVSS Start-Up Delay: 10ms**
- **Short Circuit and OLP Detect Time: 1ms**
- **Available in Green TQFN-3×3-16L Package**

APPLICATIONS

Smartphones Small Size Tablets Active Matrix OLED Displays ≤ 8"

Figure 1. Typical Application Circuit

PACKAGE/ORDERING INFORMATION

MARKING INFORMATION

NOTE: XXXXX = Date Code and Vendor Code.

X X X X X

- Date Code - Week Vendor Code

Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

RECOMMENDED OPERATING CONDITIONS

Operating Ambient Temperature Range-40℃ to +85℃ Operating Junction Temperature Range......-40℃ to +125℃

NOTE:

1. All voltages are with respect to network ground pin.

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATION

PIN DESCRIPTION

NOTE: I: input; O: output; I/O: input or output.

ELECTRICAL CHARACTERISTICS

(At T_A = +25°C, V_{IN} = 3.7V, V_{CTRL} = V_{EN VO3} = V_{IN}, V_{ELVDD} = 4.6V, V_{ELVSS} = -4.0V, V_{AVDD} = 7.6V, Full = -40°C to +85°C, unless otherwise noted.)

ELECTRICAL CHARACTERISTICS (continued)

(At T_A = +25°C, V_{IN} = 3.7V, V_{CTRL} = V_{EN VO3} = V_{IN}, V_{ELVDD} = 4.6V, V_{ELVSS} = -4.0V, V_{AVDD} = 7.6V, Full = -40°C to +85°C, unless otherwise noted.)

TIMING REQUIREMENTS

TYPICAL PERFORMANCE CHARACTERISTICS

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

FUNCTIONAL BLOCK DIAGRAM

Figure 3. SGM3833A/B Functional Block Diagram

DETAILED DESCRIPTION

The SGM3833A and SGM3833B consist of two boost converters and an inverting buck-boost converter. V_{ELVDD} is programmable in the range of 4.6V to 5.0V (default = $4.6V$). V_{ELVSS} of SGM3833A is programmable in the range of -4.8V to -0.8V (default = -4.0V). V_{ELVSS} of SGM3833B is programmable in the range of -5.4V to -1.4V (default = -4.0V) and V_{AVDD} is programmable between 5.8V and 7.9V (default = 7.6V). The transition time when V_{ELVSS} is programmed to a different value is adjustable by the CT pin capacitor.

Under-Voltage Lockout

The device has a built-in under-voltage lockout function that disables the device when the input supply voltage is too low for normal operation.

Thermal Shutdown

A thermal shutdown is implemented to prevent damage because of excessive heat and power dissipation. Once a temperature of typically +135℃ is exceeded the device shuts down (the programming is not lost). When the temperature decreases to typically +125℃ the device automatically restarts performing the start-up sequencing with the same voltages and programming as programmed before the thermal shutdown.

ELVDD Boost Converter (VO1)

The ELVDD boost converter uses a fixed-frequency valley-current-mode topology. The output voltage V_{FUVDD} is adjustable between 4.6V and 5.0V with a default voltage of 4.6V (see [Table 1](#page-12-0) or [Table 2\)](#page-13-0). In shutdown its output is fully isolated (input to output and output to input).

For the highest output voltage accuracy, connect the output sense pin (FBS) directly to the positive pin of the output capacitor. If not used, the FBS pin can be left floating or connected to ground and then the output voltage is sensed at the VO1 pin.

ELVSS Inverting Buck-Boost Converter (VO2)

The ELVSS inverting buck-boost converter uses a fixed-frequency peak-current-mode topology. V_{EUVSS} of SGM3833A is programmable in the range of -4.8V to -0.8V (default = -4.0V) and V_{EUVSS} of SGM3833B is programmable in the range of -5.4V to -1.4V (default = -4.0V) (see [Table 1](#page-12-0) and [Table 2\)](#page-13-0). In shutdown its output is fully isolated (input to output and output to input).

AVDD Boost Converter (VO3)

The AVDD boost converter uses a fixed-frequency peak-current-mode topology. The output voltage V_{AVDD} is adjustable between 5.8V and 7.9V with a default voltage of 7.6V (see [Table 1](#page-12-0) or [Table 2\)](#page-13-0). In shutdown its output is fully isolated (input to output and output to input).

Start-Up Sequence, Soft-Start and Shut-Down

The device has an implemented soft-start which limits the inrush current. When V_{IN} is applied, the output discharge is undefined until the rising edge of CTRL sets the output discharge to follow the FD pin setting. When the converters are disabled all outputs are discharged if $FD = high$ or high impedance if $FD = low$. The typical start-up sequence is shown in [Figure 4.](#page-11-0)

• Pulling EN_VO3 high starts the AVDD boost converter. V_{AVDD} follows a linear 1.5ms long voltage ramp until it reaches its default value of 7.6V, then the switch current is limited to typical 0.2A.

• Pulling CTRL high starts the ELVDD boost converter. V_{EIVDD} starts with a reduced switch current limit of 0.2A until it reaches its default voltage of 4.6V, then the full current limit is released.

• 10ms after CTRL is pulled high the ELVSS inverting buck-boost converter starts. V_{ELVSS} starts with a reduced switch current limit of 0.4A until it reaches its default voltage of -4.0V, then the full current limit is released.

Figure 4. SGM3833A/B Start-Up Sequencing Active Discharge Enabled

Figure 5. SGM3833A/B Start-Up Sequencing Active Discharge Disabled

VELVSS Transition Time Control (CT Pin)

The transition time is the time required to move V_{FUVSS} from the actual voltage level to the new programmed voltage level. The transition time can be controlled by an external capacitor connected to the CT pin. The typical 50mV CT pin comparator detects when the CT pin is connected to GND or floating, then the fastest possible transition time is used. When a capacitor is connected the R-C time constant τ sets the transition time. The output voltage is almost settled after 3τ, which means 95% of the target voltage is reached.

τ = Internal CT resistance × external capacitor

- $= R_{CT} \times C_{CT}$ = 300kΩ × 100nF
- $= 30$ ms

Figure 6. VELVSS Transition Time Control

Digital Interface (CTRL Pin)

The digital interface allows programming of the positive output voltages V_{AVDD} , V_{FIVDD} and the negative output voltage V_{ELVSS} in discrete steps. [Figure 7](#page-12-1) shows an example for SGM3833A programming V_{EIVSS} to -4.6V. [Figure 8](#page-13-1) shows an example for SGM3833B programming V_{ELVSS} to -5.2V. By default the output discharge during shutdown is controlled by the FD pin, the setting can be overwritten by digital programming. If

programming is not required the CTRL pin can also be used as a standard enable pin. Once the device is enabled the device starts with its default values (blue marked values in Table 1 or [Table 2\)](#page-13-0). The interface counts the rising edges applied to the CTRL pin and sets the new values as shown in [Table 1](#page-12-0) or [Table 2.](#page-13-0) The settings are stored in a volatile memory. The reset behavior is described in the device reset section.

Table 1. SGM3833A Programming Table

Table 2. SGM3833B Programming Table

Figure 8. SGM3833B Programming V_{ELVSS}

Short Circuit and Overload Protection

The device is protected against short of V_{AVDD} , V_{ELVDD} and V_{ELVSS} to ground. V_{ELVDD} and V_{ELVSS} are also protected when they are shorted together. A short at any converter and the V_{AVDD} overload protection shuts down the whole device, the shut-down state is latched, and input and outputs are fully disconnected. To reset the whole device V_{IN} has to cycle below under-voltage lockout or EN_VO3 and CTRL have to be low at the same time for minimum t_{OFF} . The device detects a short or an overload when one of the below conditions is fulfilled:

• V_{EIVDD} is not in regulation 10ms after V_{EIVDD} is enabled (10ms CTRL = high) \rightarrow shut-down all

 \cdot V_{FLVSS} is not in regulation 10ms after V_{ELVSS} is enabled (20ms after CTRL = high) \rightarrow shut-down all

• V(AVDD) protection is enabled when the soft-start is completed.

During Operation:

 \cdot V_{AVDD} falls below 90% of its programmed voltage longer than 1ms \rightarrow shut-down all

• V_{FIVDD} falls below 90% of its programmed voltage longer than $1ms \rightarrow shut$ -down all

• V_{FUVSS} rises above 500mV of its programmed voltage longer than $1ms \rightarrow shut$ -down all

Enable/Disable Active Discharge During Shutdown

The active discharge during shutdown can be enabled and disabled by the FD pin or by programming. The programming overwrites the FD pin setting until the function is reset.

• FD pin connected to GND or 51 CTRL pulses \rightarrow Active discharge is disabled and all outputs are high impedance.

• FD pin connected to HIGH $(V_H > 1.2V)$ or 50 CTRL pulses \rightarrow Active discharge is enabled and all outputs are discharged.

Device Reset

• A power cycle resets all settings to default values as well as the short-circuit protection.

• Enabling the V_{EIVDD} converter (first rising edge of CTRL) resets the output discharge \rightarrow Output discharge is controlled by FD pin.

• When CTRL is low for t_{OFF} then V_{FIVSS} is reset to default value \rightarrow -4.0V.

• EN_VO3 and CTRL are low at the same time for t_{DEF}

 \rightarrow Short circuit protection is reset.

Operation with V_{IN} < 2.9V

The recommended minimum input supply voltage for full performance is 2.9V. The device continues to operate with input supply voltages below 2.9V, however, full performance is not ensured. The device does not operate with input supply voltages below the under-voltage Lockout threshold.

APPLICATION INFORMATION

[Figure 1](#page-0-0) shows a typical application circuit suitable for supplying AMOLED displays in smartphone applications. The circuit is designed to operate from a single-cell Li-Ion battery and generates positive output voltages V_{AVDD} of 7.6V and V_{ELVDD} of 4.6V as well as a negative output voltage V_{ELVSS} of -4.0V. ELVDD and ELVSS are capable of supplying up to 400mA of output current.

For this design example, use the following input parameters in [Table 3.](#page-15-0)

Table 3. Design Parameters

In order to maximize performance, the device has been optimized for use with a relatively narrow range of component values. The V_{AVDD} boost converter typically requires a 10µH inductor, V_{FIVDD} and V_{FIVSS} require a 4.7µH inductor. Ceramic capacitors are usually used for input and output capacitors. It is recommended to use the suggested values in all applications. Customers using other values are strongly recommended to characterize circuit performance on a case-by-case basis.

ELVDD Boost Converter (VO1)

Inductor Selection

The main parameter for the inductor selection is the inductor saturation current, which must be higher than the peak switch current. Inductors with lower saturation current than the minimum switch current limit can be used when the maximum output current is not required, however a minimum saturation current of 0.5A is required to ensure proper startup. The minimum required saturation current is calculated by the peak inductor current formula.

The inductors DC resistance as well as its core losses affect the efficiency. Lower DC resistance results in higher high load efficiency. The core losses are especially important for light load efficiency. The core material as well as the inductors physical size has an influence on the core losses. The higher the quality factor Q of the inductor at the switching frequency (1.5MHz) the lower the core losses. [Table 4](#page-16-0) shows examples of suitable inductors, equivalent parts can be used.

- Minimum 3.3µH, maximum 6.1µH inductance.
- Minimum 0.5A saturation current, for full output current capability 1.3A.

• Minimum V_{IN} and maximum I_{OUT} must be taken to calculate the required saturation current.

• Duty Cycle:

$$
D = \frac{V_{\text{OUT}} - V_{\text{IN}} \times \eta}{V_{\text{OUT}}}
$$

where

 V_{IN} is the boost converter input supply voltage. V_{OUT} is the boost converter output voltage. η is the boost converter efficiency

• Peak Inductor Current:

$$
I_{(SW)M} = \frac{I_{OUT}}{1-D} + \frac{V_{IN} \times D}{2 \times f \times L}
$$

where

 I_{OUT} is the boost converter output current. f = 1.5MHz (the boost converter switching frequency). L is the boost converter inductance (4.7µH).

Capacitor Selection

The main parameter for the capacitor selection is the capacitance at the operating voltage. The more voltage is applied at the capacitor the lower is its resulting capacitance (DC-bias effect), also temperature and AC-Voltage changes the capacitance, however the DC-bias effect is dominant. For best voltage filtering (lowest voltage ripple), low ESR capacitors are recommended. [Table 5](#page-16-1) and [Table 6](#page-16-2) show examples of suitable capacitors, equivalent parts can be used.

Input Capacitor:

- Minimum 2.5μF resulting capacitance.
- Minimum 6.3V voltage rating.

Output Capacitor:

- Minimum 2.5μF, maximum 24μF resulting capacitance.
- Minimum 6.3V voltage rating.

Table 4. ELVDD Boost Converter (VO1) Inductor Selection

Table 5. Input Capacitor Selection ELVDD Boost Converter (VO1)

CAPACITANCE	VOLTAGE RATING	MANUFACTURER	PART NUMBER	SIZE
10uF	6.3V	Murata	GRM188R60J106ME84	0603
$10\mu F$	10V	Murata	GRM219R61A106ME47	0805
$22\mu F$	10V	Samsung	CL21A226MPCLRNC	0805

Table 6. Output Capacitor Selection ELVDD Boost Converter (VO1)

ELVSS Inverting Buck-Boost Converter (VO2)

Inductor Selection

The main parameter for the inductor selection is the inductor saturation current, which must be higher than the peak switch current. Inductors with lower saturation current than the minimum switch current limit can be used when the maximum output current is not required, however a minimum saturation current of 0.5A is required to ensure proper startup. The minimum required saturation current is calculated by the peak inductor current formula.

The inductors DC resistance as well as its core losses affect the efficiency. Lower DC resistance results in higher high load efficiency. The core losses are especially important for light load efficiency. The core material as well as the inductors physical size has an influence on the core losses. The higher the quality factor Q of the inductor at the switching frequency (1.5MHz) the lower the core losses. [Table 7](#page-17-0) shows examples of suitable inductors, equivalent parts can be used.

• Minimum 3.3µH, maximum 6.1µH inductance.

• Minimum 0.5A saturation current, for full output current capability 1.5A.

• Minimum V_{IN} and maximum I_0 must be taken to calculate the required saturation current.

• Duty Cycle:

$$
D = \frac{V_{\text{OUT}}}{V_{\text{OUT}} - V_{\text{IN}} \times \eta}
$$

where

 V_{IN} is the inverting buck-boost converter input supply voltage.

 V_{OUT} is the inverting buck-boost converter output voltage.

η is the inverting buck-boost converter efficiency.

• Peak Inductor Current:

$$
I_{(SW)M} = \frac{I_{OUT}}{1-D} + \frac{V_{IN} \times D}{2 \times f \times L}
$$

where

 I_{OUT} is the inverting buck-boost converter output current.

f = 1.5MHz (the inverting buck-boost converter switching frequency).

L is the inverting buck-boost converter inductance (4.7µH).

Capacitor Selection

The main parameter for the capacitor selection is the capacitance at the operating voltage. The more voltage is applied at the capacitor the lower is its resulting capacitance (DC-bias effect), also temperature and AC-voltage changes the capacitance. However the DC-bias effect is dominant. For best voltage filtering (lowest voltage ripple), low ESR capacitors are recommended. [Table 8](#page-17-1) and [Table 9](#page-17-2) show examples of suitable capacitors, equivalent parts can be used.

Input Capacitor:

- Minimum 2.5μF resulting capacitance.
- Minimum 6.3V voltage rating.
- Output Capacitor:
- Minimum 2.5μF, maximum 24μF resulting capacitance.
- Minimum 10V voltage rating, when maximum -6V are used also 6.3V rated capacitors can be used.

Table 7. ELVSS Inverting Buck-Boost Converter (VO2) Inductor Selection

INDUCTANCE	I sat	DCR	MANUFACTURER	PART NUMBER	DIMENSIONS
4.7 _µ H	1.9A	$200 \text{m}\Omega$	TOKO	DFE252012C-4R7M	2.5 mm \times 2.0mm \times 1.2mm
	2.2A	165mΩ	TOKO	DFE252012P-4R7M	2.5 mm \times 2.0mm \times 1.2mm
	1.5A	$175m\Omega$	AI PS	GLCLM4R701A	2.5 mm \times 2.0mm \times 1.2mm
	l .5A	$230 \text{m}\Omega$	ALPS	GLCLK4R701A	2.5 mm \times 2.0mm \times 1mm

Table 8. Input Capacitor Selection ELVSS Inverting Buck-Boost Converter (VO2)

Table 9. Output Capacitor Selection ELVSS Inverting Buck-Boost Converter (VO2)

AVDD Boost Converter (VO3)

Inductor Selection

The main parameter for the inductor selection is the inductor saturation current, which must be higher than the peak switch current. Inductors with lower saturation current than the minimum switch current limit can be used when the maximum output current is not required, however a minimum saturation current of 0.2A is required to ensure proper startup. The minimum required saturation current is calculated by the peak inductor current formula.

The inductors DC resistance as well as its core losses affect the efficiency. Lower DC resistance results in higher high load efficiency. The core losses are especially important for light load efficiency. The core material as well as the inductors physical size has an influence on the core losses. The higher the quality factor Q of the inductor at the switching frequency (1.5MHz) the lower the core losses. [Table 10](#page-18-0) shows examples of suitable inductors, equivalent parts can be used.

- Minimum 7µH, maximum 13µH inductance.
- Minimum 0.2A saturation current, for full output current capability 0.25A.
- Minimum V_{IN} and maximum I_{Ω} must be taken to calculate the required saturation current.
- Duty Cycle:

$$
D = \frac{V_{\text{OUT}} - V_{\text{IN}} \times \eta}{V_{\text{OUT}}}
$$

where

 V_{IN} is the boost converter input supply voltage. V_{OUT} is the boost converter output voltage. η is the boost converter efficiency

• Peak Inductor Current:

$$
I_{(SW)M} = \frac{I_{OUT}}{1-D} + \frac{V_{IN} \times D}{2 \times f \times L}
$$

where

 I_{OUT} is the boost converter output current. f = 1.5MHz (the boost converter switching frequency). L is the boost converter inductance (10µH)

Capacitor Selection

The main parameter for the capacitor selection is the capacitance at the operating voltage. The more voltage is applied at the capacitor the lower is its resulting capacitance (DC-bias effect), also temperature and AC-Voltage changes the capacitance, however the DC-bias effect is dominant. For best voltage filtering (lowest voltage ripple), low ESR capacitors are recommended. [Table 11](#page-18-1) and [Table 12](#page-18-2) show examples of suitable capacitors, equivalent parts can be used.

Input Capacitor:

- Minimum 2.5μF resulting capacitance.
- Minimum 6.3V voltage rating.

Output Capacitor:

- Minimum 2.5μF, maximum 24μF resulting capacitance.
- Minimum 10V voltage rating .

Table 10. AVDD Boost Converter (VO3) Inductor Selection

INDUCTANCE	I _{SAT}	DCR	MANUFACTURER	PART NUMBER	DIMENSIONS
10uH	1.3A	$400 \text{m}\Omega$	токо	DFE252012C-100M	2.5 mm × 2.0mm × 1.2mm
	1.2A	530 $m\Omega$	TOKO	DFE252010C-100M	2.5 mm \times 2.0mm \times 1mm
	0.75A	600m Ω	Taiyo Yuden	MDKK2020T-100MM	$2mm \times 2mm \times 1mm$
	0.8A	$359m\Omega$	CYNTEC	SDET25201B-100MS	2.5 mm × 2mm × 1.2mm
	0.48A	817mΩ	CYNTEC	SDER20121T-100MS	2.0 mm \times 1.2mm \times 1mm

Table 11. Input Capacitor Selection AVDD Boost Converter (VO3)

Table 12. Output Capacitor Selection AVDD Boost Converter (VO3)

Power Supply Recommendations

The SGM3833A and SGM3833B device are designed to operate with input supplies from 2.9V to 4.5V. The input supply should be stable and free of noise if the device's full performance is to be achieved. If the input supply is located more than a few centimeters away from the device, additional bulk capacitance may be required. The input capacitance shown in the Application Information is sufficient for typical applications.

Layout Guideline

The PCB layout is an important step in the power supply design. An incorrect layout could cause converter instability, load regulation problems, noise, and EMI issues. Especially with a switching DC/DC converter at high load currents, too thin PCB traces can cause significant voltage spikes. Good grounding becomes important as well. If possible a common

ground plane to minimize ground shifts between analog ground (GND) and power ground (PGND) is recommended.

• Place the input capacitor on PVIN and the output capacitor on VO2 as close as possible to the device. Use short and wide traces to connect the input capacitor on PVIN and the output capacitor on VO2.

• Place the output capacitor on VO1 and VO3 as close as possible to the device. Use short and wide traces to connect the output capacitor on VO1 and VO3.

• Connect the ground of the CT capacitor with AGND (pin 7) directly.

• Connect input ground and output ground on the same board layer, not through via hole.

• Connect AGND, PGND1 and PGND2 with the exposed thermal pad.

REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

PACKAGE OUTLINE DIMENSIONS

TQFN-3×3-16L

RECOMMENDED LAND PATTERN (Unit: mm)

TAPE AND REEL INFORMATION

REEL DIMENSIONS

NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

CARTON BOX DIMENSIONS

NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

